

Product data sheet

1. General description

Planar passivated AC Thyristor Triac power switch in a SOT186A (TO-220F) "full pack" plastic package with self-protective capabilities against low and high energy transients.

2. Features and benefits

- Clamping structure ensuring safe high over-voltage withstand capability
- Direct interfacing with low power drivers and microcontrollers
- Full cycle AC conduction
- Isolated mounting base package
- Over-voltage withstand capability to IEC 61000-4-5
- Pin compatible with standard triacs
- Planar passivated for voltage ruggedness and reliability
- Safe clamping capability for low energy over-voltage transients
- Self-protective turn-on during high energy voltage transients
- Sensitive gate for easy logic level triggering
- Triggering in three quadrants only
- Very high immunity to false turn-on by dV/dt

3. Applications

- AC fan, pump and compressor controls
- Highly inductive, resistive and safety loads
- Large and small appliances (White Goods)
- Reversing induction motor controls

4. Quick reference data

| Table 1. Qui | ck reference data | | | | | |
|---------------------|--|---|-----|-----|-----|------|
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
| V _{DRM} | repetitive peak off- state voltage | | - | - | 800 | V |
| I _{TSM} | non-repetitive peak on- state current | full sine wave; $T_{j(init)} = 25 \text{ °C};$ $t_p = 20 \text{ ms}; \text{ Fig. 4}; \text{ Fig. 5}$ | - | - | 35 | A |
| Tj | junction temperature | | - | - | 125 | °C |
| I _{T(RMS)} | RMS on-state current | full sine wave; $T_h \le 94$ °C; Fig. 1; Fig. 2; Fig. 3 | - | - | 4 | A |





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| Symbol | Parameter | Conditions | Min | Тур | Мах | Unit |
|-----------------------------------|---------------------------------------|---|-----|-----|-----|------|
| V _{PP} | peak pulse voltage | T _j = 25 °C; non-repetitive, off-state; Fig. 6 | - | - | 2 | kV |
| Static chara | acteristics | · · · · | | | | |
| I _{GT} gate trigger curr | gate trigger current | V_D = 12 V; I _T = 100 mA; LD+ G+; T _j = 25 °C; <u>Fig. 8</u> | - | - | 10 | mA |
| | | V _D = 12 V; I _T = 100 mA; LD+ G-; T _j = 25 °C; <u>Fig. 8</u> | - | - | 10 | mA |
| | | V_D = 12 V; I _T = 100 mA; LD- G-; T _j = 25 °C; <u>Fig. 8</u> | - | - | 10 | mA |
| V _{CL} | clamping voltage | I _{CL} = 0.1 mA; t _p = 1 ms; T _j = 25 °C | 850 | - | - | V |
| Dynamic cl | narateristics | | I | | | |
| dV _D /dt | rate of rise of off-state voltage | V_{DM} = 536 V; T _j = 125 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit; Fig. 13 | 500 | - | - | V/µs |
| dI _{com} /dt | rate of change of commutating current | V_D = 400 V; T _j = 125 °C; I _{T(RMS)} = 4 A; dV _{com} /dt = 1 V/µs; gate open circuit; Fig. 14; Fig. 15 | 8 | - | - | A/ms |

5. Pinning information

| | information | | |
|--------|-------------------------|--------------------------------|---|
| Symbol | Description | Simplified outline | Graphic symbol |
| СМ | common | mb | LD |
| LD | load | | _G |
| G | gate | | СМ |
| n.c. | mounting base; isolated | | 003aaf296 |
| | | | |
| | CM LD G | CM common LD load G gate | CM common LD load G gate n.c. mounting base; isolated |

6. Ordering information

| Table 3. Ordering information | | | | | | | |
|-------------------------------|---------|---|---------|--|--|--|--|
| Type number | Package | | | | | | |
| | Name | Description | Version | | | | |
| ACTT4X-800E | TO-220F | plastic single-ended package; isolated heatsink mounted; 1 mounting hole; 3-lead TO-220 "full pack" | SOT186A | | | | |

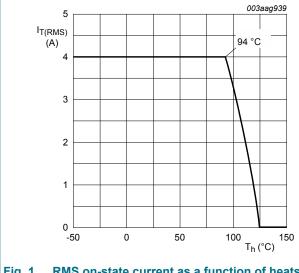
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7. Limiting values

Table 4.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|---------------------|--------------------------------------|---|-----|-----|------------------|
| V _{DRM} | repetitive peak off-state voltage | | - | 800 | V |
| I _{T(RMS)} | RMS on-state current | full sine wave; $T_h \le 94$ °C; Fig. 1; Fig. 2; Fig. 3 | - | 4 | A |
| I _{TSM} | non-repetitive peak on-state current | full sine wave; $T_{j(init)} = 25 \text{ °C};$ $t_p = 20 \text{ ms}; \text{Fig. 4}; \text{Fig. 5}$ | - | 35 | A |
| | | full sine wave; $T_{j(init)}$ = 25 °C; t_p = 16.7 ms | - | 39 | A |
| l ² t | l ² t for fusing | t _p = 10 ms; sine-wave pulse | - | 6 | A ² s |
| dI _T /dt | rate of rise of on-state current | I_T = 6 A; I_G = 0.2 A; dI_G/dt = 0.2 A/µs | - | 100 | A/µs |
| I _{GM} | peak gate current | t = 20 μs | - | 2 | А |
| P _{GM} | peak gate power | | - | 5 | W |
| P _{G(AV)} | average gate power | over any 20 ms period | - | 0.5 | W |
| T _{stg} | storage temperature | | -40 | 150 | °C |
| Tj | junction temperature | | - | 125 | °C |
| V _{PP} | peak pulse voltage | T _j = 25 °C; non-repetitive, off-state; Fig. 6 | - | 2 | kV |





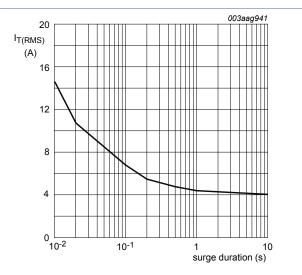
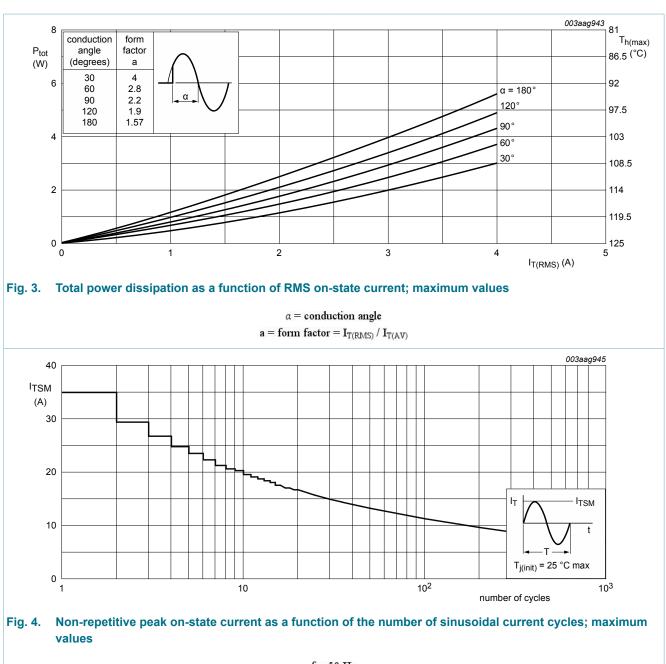


Fig. 2. on-state current as a function of surge duration; maximum values

f = 50 Hz; $T_h = 94$ °C

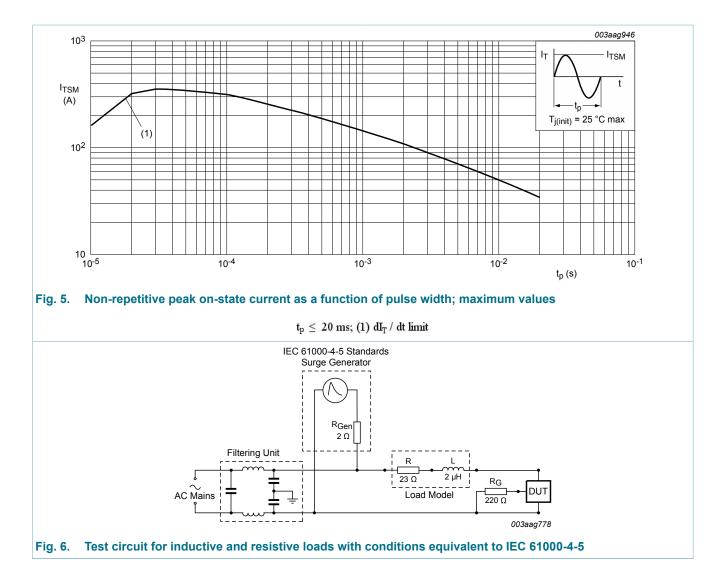
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f = 50 Hz

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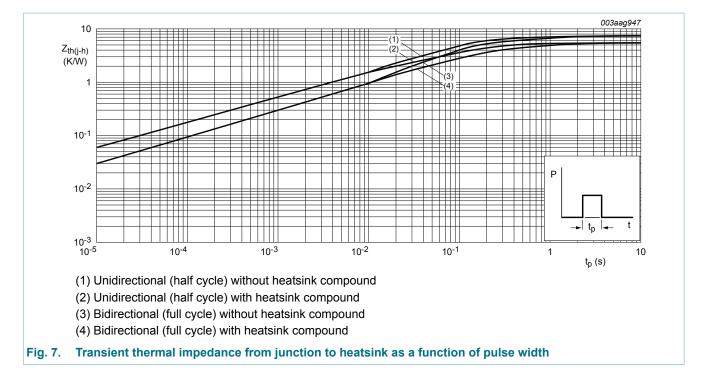
8. Thermal characteristics

Table 5.Thermal characteristics

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|----------------------|---|---|-----|-----|-----|------|
| R _{th(j-h)} | thermal resistance from junction to | full cycle or half cycle; with heatsink compound; Fig. 7 | - | - | 5.5 | K/W |
| | heatsink | full cycle or half cycle; without heatsink compound; Fig. 7 | - | - | 7.2 | K/W |
| R _{th(j-a)} | thermal resistance from junction to ambient | in free air | - | 55 | - | K/W |

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9. Isolation characteristics

| Table 6. Isol | ation characteristics | | | | | |
|------------------------|-----------------------|--|-----|-----|------|------|
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
| V _{isol(RMS)} | RMS isolation voltage | 50 Hz \leq f \leq 60 Hz; RH \leq 65 %; T _h = 25 °C; sinusoidal waveform; from all pins to external heatsink; clean and dust free | - | - | 2500 | V |
| C _{isol} | isolation capacitance | T _h = 25 °C; from LD pin to external heatsink; f = 1 MHz | - | 10 | - | pF |

10. Characteristics

| Table 7. Ch | aracteristics | | | | | | | |
|------------------------|----------------------|--|--|-----|-----|-----|------|--|
| Symbol | Parameter | Conditions | | Min | Тур | Мах | Unit | |
| Static characteristics | | | | | | | | |
| I _{GT} | gate trigger current | V _D = 12 V; I _T = 100 mA; LD+ G+; T _j = 25 °C; <u>Fig. 8</u> | | - | - | 10 | mA | |
| | | $V_D = 12 \text{ V}; \text{ I}_T = 100 \text{ mA}; \text{ LD+ G-};$ $T_j = 25 \text{ °C}; \text{ Fig. 8}$ | | - | - | 10 | mA | |
| | | V _D = 12 V; I _T = 100 mA; LD- G-; T _j = 25 °C; <u>Fig. 8</u> | | - | - | 10 | mA | |

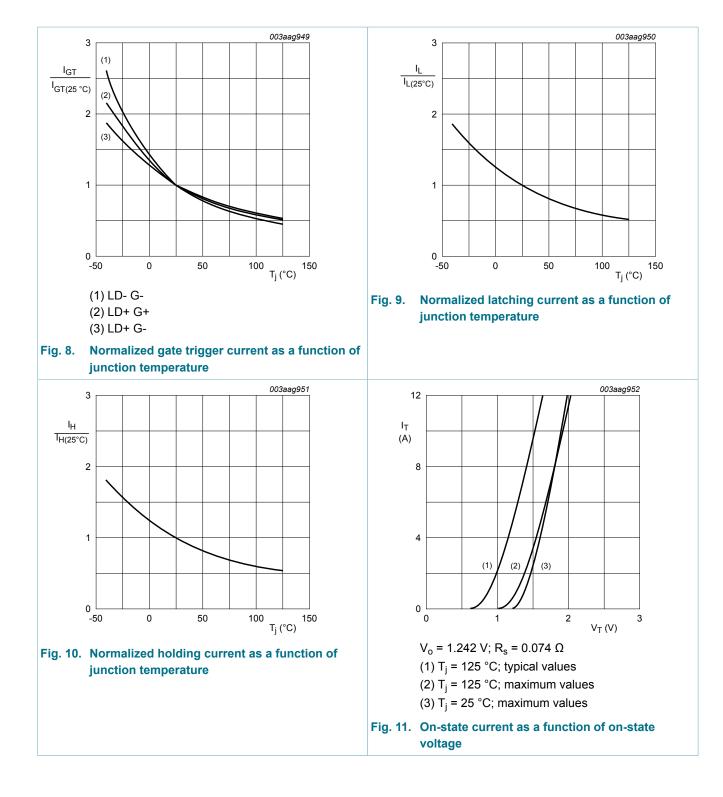
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| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|----------------------------------|---------------------------------------|---|-----|------|-----|------|
| ΙL | latching current | V _D = 12 V; I _G = 100 mA; LD+ G+; T _j = 25 °C; <u>Fig. 9</u> | - | - | 30 | mA |
| | | V _D = 12 V; I _G = 100 mA; LD+ G-; T _j = 25 °C; <u>Fig. 9</u> | - | - | 40 | mA |
| | | V _D = 12 V; I _G = 100 mA; LD- G-; T _j = 25 °C; <u>Fig. 9</u> | - | - | 30 | mA |
| I _H | holding current | V _D = 12 V; T _j = 25 °C; <u>Fig. 10</u> | - | - | 20 | mA |
| V _T | on-state voltage | I _T = 6 A; T _j = 25 °C; <u>Fig. 11</u> | - | - | 1.7 | V |
| V _{GT} | gate trigger voltage | V _D = 12 V; I _T = 100 mA; T _j = 25 °C; Fig. 12 | - | 0.8 | 1 | V |
| | | V _D = 400 V; I _T = 100 mA; T _j = 125 °C; Fig. 12 | 0.2 | 0.45 | - | V |
| I _D off-state current | off-state current | V _D = 800 V; T _j = 25 °C | - | - | 10 | μA |
| | | V _D = 800 V; T _j = 125 °C | - | - | 0.5 | mA |
| V _{CL} | clamping voltage | I _{CL} = 0.1 mA; t _p = 1 ms; T _j = 25 °C | 850 | - | - | V |
| Dynamic cl | narateristics | · · · | I | | _ | |
| dV _D /dt | rate of rise of off-state voltage | V_{DM} = 536 V; T _j = 125 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit; Fig. 13 | 500 | - | - | V/µs |
| | rate of change of commutating current | $V_{D} = 400 \text{ V}; \text{T}_{\text{j}} = 125 ^{\circ}\text{C}; \text{I}_{\text{T}(\text{RMS})} = 4 \text{ A};$ dV _{com} /dt = 20 V/µs; (snubberless condition); gate open circuit; <u>Fig. 14</u> ; <u>Fig. 15</u> | 4 | - | - | A/ms |
| | | V_D = 400 V; T _j = 125 °C; I _{T(RMS)} = 4 A; dV _{com} /dt = 10 V/µs; gate open circuit; Fig. 14; Fig. 15 | 5 | - | - | A/ms |
| | | $V_D = 400 \text{ V}; \text{T}_\text{j} = 125 ^\circ\text{C}; \text{I}_\text{T(RMS)} = 4 \text{ A};$ $dV_\text{com}/dt = 1 \text{V}/\mu\text{s}; \text{ gate open circuit};$ $\overline{\text{Fig. 14}; \text{ Fig. 15}}$ | 8 | - | - | A/ms |

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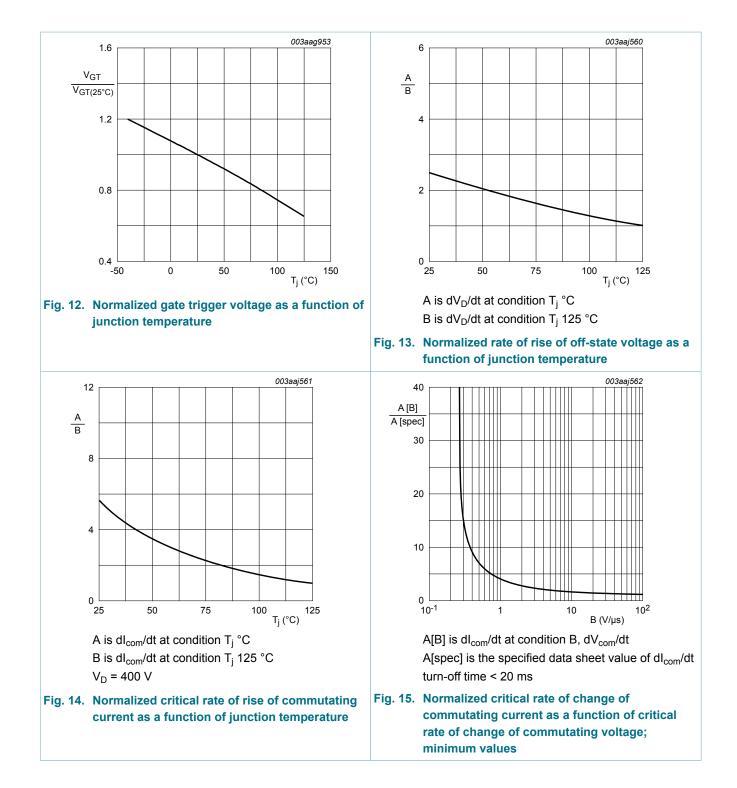


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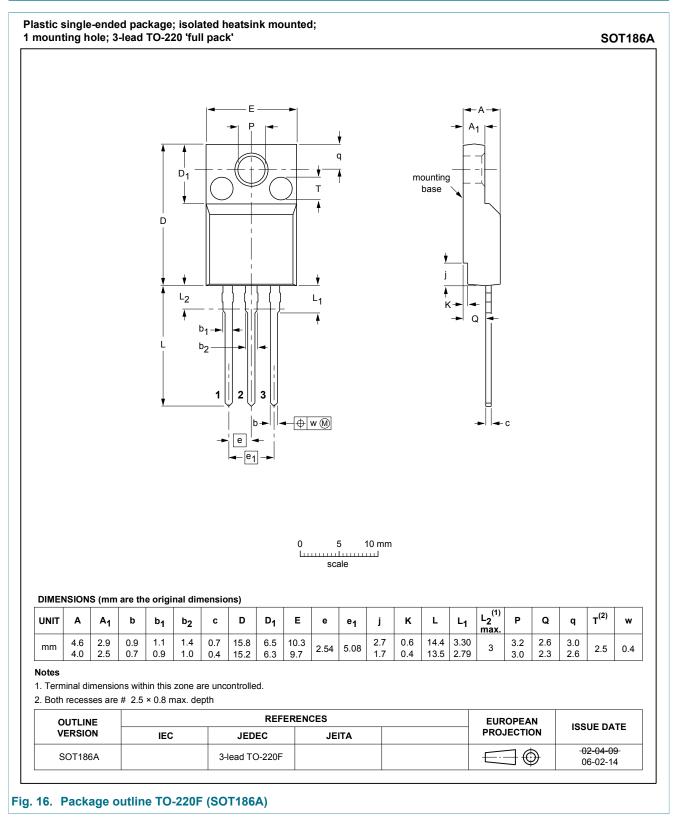
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11. Package outline



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12. Legal information

12.1 Data sheet status

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|--------------------------------------|-------------------------------|---|
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